NSN 5961-01-069-3007

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-069-3007 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.975 inches **Overall Height:** 0.275 inches **Overall Width:** 0.725 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 35.0 collector to emitter voltage/static/base open and 60.0 collector to emitter voltage, dc with base short-circuited to emitter and 4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector preset **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 87990-755002a7632 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:**